

Data sheet acquired from Harris Semiconductor SCHS184C

September 1997 - Revised February 2004

High-Speed CMOS Logic Octal D-Type Flip-Flop With Data Enable

Features

- Buffered Common Clock
- Buffered Inputs
- Typical Propagation Delay at C_L = 15pF, $V_{CC} = 5V, T_A = 25^{\circ}C$
 - 14 ns (HC Types
 - 16 ns (HCT Types)
- Fanout (Over Temperature Range)
 - Standard Outputs........... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I_I \leq 1 μ A at V_{OL}, V_{OH}

Description

The 'HC377 and 'HCT377 are octal D-type flip-flops with a buffered clock (CP) common to all eight flip-flops. All the flipflops are loaded simultaneously on the positive edge of the clock (CP) when the Data Enable (\overline{E}) is Low.

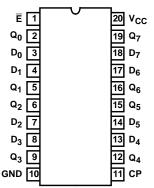
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC377F3A	-55 to 125	20 Ld CERDIP
CD54HCT377F3A	-55 to 125	20 Ld CERDIP
CD74HC377E	-55 to 125	20 Ld PDIP
CD74HC377M	-55 to 125	20 Ld SOIC
CD74HC377M96	-55 to 125	20 Ld SOIC
CD74HC377PW	-55 to 125	20 Ld TSSOP
CD74HC377PWR	-55 to 125	20 Ld TSSOP
CD74HCT377E	-55 to 125	20 Ld PDIP
CD74HCT377M	-55 to 125	20 Ld SOIC
CD74HCT377M96	-55 to 125	20 Ld SOIC

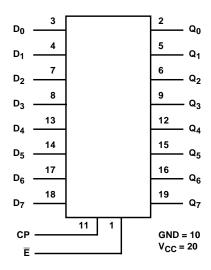
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel.

Pinout

CD54HC377, CD54HCT377 (CERDIP) CD74HC377 (PDIP. SOIC. TSSOP) **CD74HCT377** (PDIP, SOIC) **TOP VIEW**



Functional Diagram



TRUTH TABLE

		OUPUTS		
OPERATING MODE	СР	Ē	D _n	Q _n
Load "1"	1	I	h	Н
Load "0"	1	I	I	L
Hold (Do Nothing)	1	h	Х	No Change
	Х	Н	X	No Change

H = High Voltage Level Steady State.

h = High Voltage Level One Set-up Time Prior to the Low to High Clock Transition.

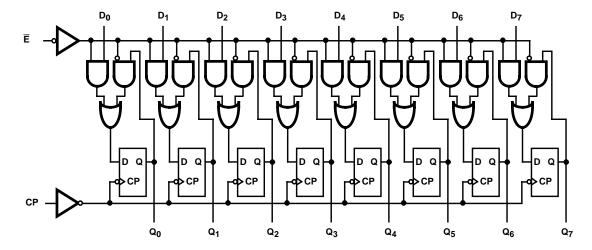
L = Low Voltage Level Steady State.

I = Low Voltage Level One Set-up Time Prior to the Low to High Clock Transition.

X = Don't Care.

 \uparrow = Low to High Clock Transition.

Logic Diagram



$\label{eq:absolute Maximum Ratings} \begin{tabular}{ll} Absolute Maximum Ratings \\ DC Supply Voltage, V_{CC} -0.5V to 7V \\ DC Input Diode Current, I_{IK} For $V_I < -0.5V \ or $V_I > V_{CC} + 0.5V$ <math>\pm 20 mA$ \\ DC Output Diode Current, I_{OK} For $V_O < -0.5V \ or $V_O > V_{CC} + 0.5V$ <math>\pm 20 mA$ \\ DC Output Source or Sink Current per Output Pin, I_O For $V_O > -0.5V \ or $V_O < V_{CC} + 0.5V$ <math>\pm 25 mA$ \\ DC V_{CC} or Ground Current, I_{CC} or I_{GND} <math>\pm 50 mA$ \\ \hline \end{tabular}$

Temperature Range (T_A)-55°C to 125°C

 2V
 1000ns (Max)

 4.5V
 500ns (Max)

 6V
 400ns (Max)

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (ºC/W)
E (PDIP) Package	. 69
M (SOIC) Package	
PW (TSSOP) Package	. 83
Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

Supply Voltage Range, V_{CC}

Input Rise and Fall Time

		TE: CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	VoH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
OWOO LOAGS			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE LOGUS			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Edads			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
I I L Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	IĮ	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

DC Electrical Specifications (Continued)

		TE: CONDI	_	Vcc		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES	-		-		-	-	-	-	-			
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
Ē	1.5
СР	0.5
All D _n Inputs	0.25

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{o}C.$

Prerequisite for Switching Specifications

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES												
Maximum Clock	f _{MAX}	-	2	6	-	-	5	-	4	-	MHz	
Frequency			4.5	30	-	-	25	-	20	-	MHz	
			6	35	-	-	29	-	23	-	MHz	
Clock Pulse Width	t _W	-	2	80	-	-	100	-	120	-	ns	
			4.5	16	-	-	20	-	24	-	ns	
			6	14	-	-	17	-	20	-	ns	

^{2.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Prerequisite for Switching Specifications (Continued)

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125 ⁰ C	-
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Set-up Time,	t _{SU}	-	2	60	-	-	75	-	90	-	ns
Ē, Data to CP			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
Hold Time,	t _H	-	2	3	-	-	3	-	3	-	ns
Data to CP			4.5	3	-	-	3	-	3	-	ns
			6	3	-	-	3	-	3	-	ns
Hold Time,	t _H	-	2	5	-	-	5	-	5	-	ns
E to CP			4.5	5	-	-	5	-	5	-	ns
			6	5	-	-	5	-	5	-	ns
HCT TYPES											
Maximum Clock Frequency	fMAX	-	4.5	25	-	-	20	-	16	-	MHz
Clock Pulse Width	t _W	-	4.5	20	-	-	25	-	30	-	ns
Set-up, Time E, Data to CP	tsu	-	4.5	12	-	-	15	-	18	-	ns
Hold Time, Data to CP	t _H	-	4.5	3	-	-	3	-	3	-	ns
Hold Time, E to CP	tH	-	4.5	5	-	-	5	-	5	-	ns

Switching Specifications Input $t_{\text{r}}, \, t_{\text{f}} = 6 \text{ns}$

		TEST V _{CC} 25°C			-	с то °С	-55°C TO 125°C		4		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	МАХ	MIN	MAX	UNITS
HC TYPES											
Propagation Delay (Figure 1)	t _{PLH} ,	$C_L = 50pF$	2	-	-	175	-	220	-	265	ns
CP to Q	t _{PHL}		4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Maximum Clock Frequency	f _{MAX}	C _L =15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L =15pF	5	-	31	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay (Figure 1)	t _{PLH} ,	C _L = 50pF	4.5	-	-	38	-	48	-	57	ns
CP to Q	t _{PHL}	C _L =15pF	5	-	16	-	-	-	-	-	ns
Output Transition Time (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST	V _{CC}		25°C		-40 ⁰ 85	С ТО °С	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Maximum Clock Frequency	f _{MAX}	C _L =15pF	5	-	50	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L =15pF	5	1	35	1	1	-	-	-	pF

NOTES:

- 3. C_{PD} is used to determine the dynamic power consumption, per flip-flop.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i = Input$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.

Test Circuits and Waveforms

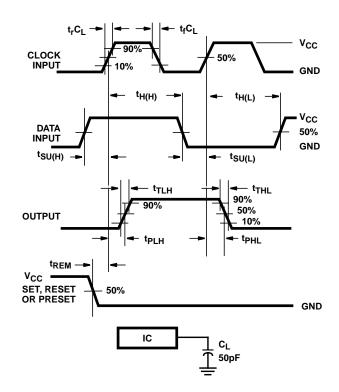


FIGURE 1. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

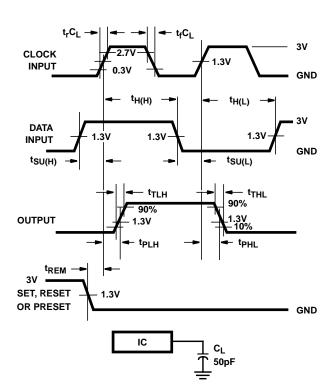


FIGURE 2. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8976901RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8976901RA CD54HCT377F3A
CD54HC377F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8780701RA CD54HC377F3A
CD54HC377F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8780701RA CD54HC377F3A
CD54HCT377F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8976901RA CD54HCT377F3A
CD54HCT377F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8976901RA CD54HCT377F3A
CD74HC377E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC377E
CD74HC377E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC377E
CD74HC377M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	HC377M
CD74HC377M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC377M
CD74HC377M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC377M
CD74HC377PW	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-55 to 125	HJ377
CD74HC377PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ377
CD74HC377PWR.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ377
CD74HCT377E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT377E
CD74HCT377E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT377E
CD74HCT377M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	HCT377M
CD74HCT377M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT377M
CD74HCT377M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT377M

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC377, CD54HCT377, CD74HC377, CD74HCT377:

Catalog: CD74HC377, CD74HCT377

Military: CD54HC377, CD54HCT377

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC377M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74HC377PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
CD74HCT377M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

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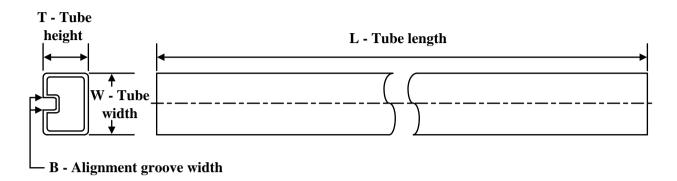
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC377M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74HC377PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
CD74HCT377M96	SOIC	DW	20	2000	356.0	356.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC377E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HC377E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT377E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT377E.A	N	PDIP	20	20	506	13.97	11230	4.32

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



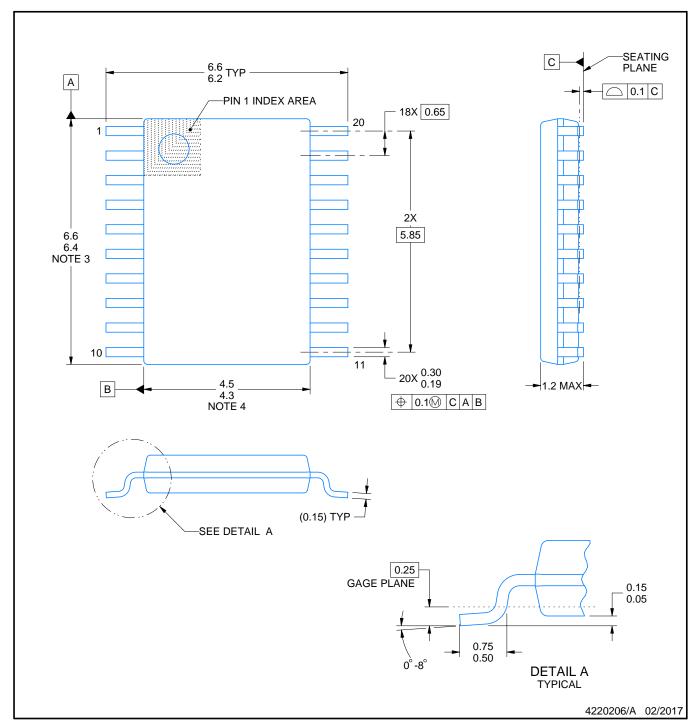
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



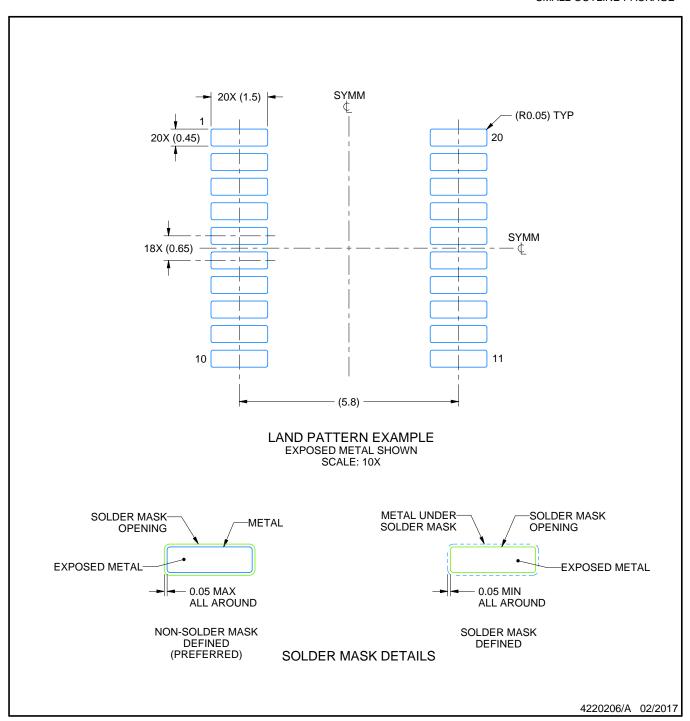
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



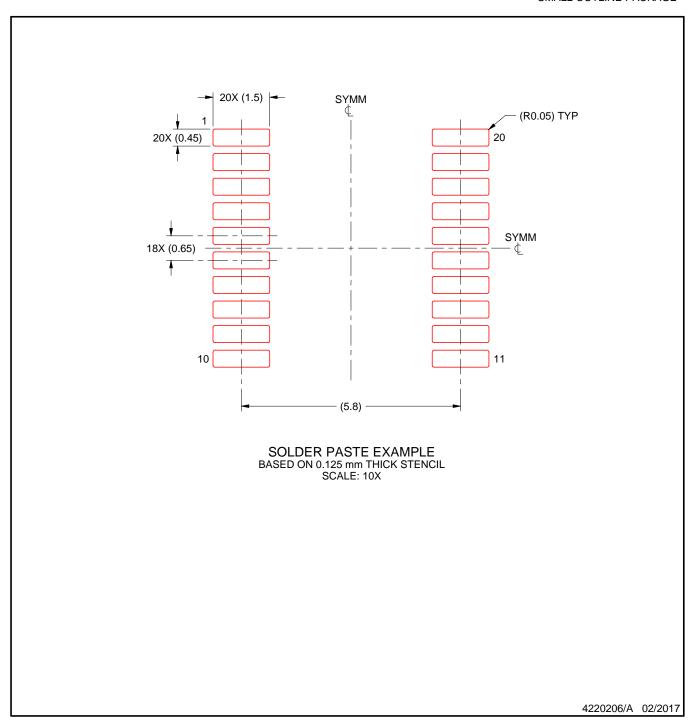
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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